AIC1899
1.0MHz Current-Mode Step-Up DC/DC Converter

## FEATURES

- Fixed Frequency 1.0 MHz Current-Mode PWM Operation.
- Adjustable Output Voltage up to 24 V .
- 2.5V to 5.5V Input Range.
- Maximum 0.1 A A Shutdown Current.
- Programmable Soft-Start.
- Tiny Inductor and Capacitors are allowed.
- Space-Saving TSOT-23-6 and SOT-23-6 Package.


## APPLICATIONS

- OLED Driver for MP3 Player
- White LED Backlight


## DESCRIPTION

The current-mode pulse-width modulation, AIC1899, step up converter is designed for MP3 player. The built-in high voltage N -channel MOSFET allows AIC1899 for step-up applications with up to 24 V output voltage, and other low-side switching DC/DC converter.

The high switching frequency allows the use of small external components. The Soft-Start function is programmable with an external capacitor, which sets the input current ramp rate.

The AIC1899 is available in a space-saving TSOT-23-6 and SOT-23-6 package.

## TYPICAL APPLICATION CIRCUIT



Fig. 1 Typical Step up Application Circuit

## ■ ORDERING INFORMATION

```
AIC1899XXXX
    |
                                TR:TAPE & REEL
                                BG:BAG
                        PACKAGE TYPE
                        G: SOT-23-6
                        K: TSOT-23-6
                        P: LEAD FREE COMMERCIAL
                G: GREEN PACKAGE
Example: AIC1899PGTR
-> in Lead Free SOT-23-6 Package & Tape
    & Reel Packing Type
    AIC1899PKTR
    -> in Lead Free TSOT-23-6 Package & Tape
        & Reel Packing Type
```


## - TSOT-23-6 Marking

| Part No. | Marking | Part No. | Marking |
| :---: | :---: | :---: | :---: |
| AIC1899PK | 899PK | AIC1899GK | 899GK |

## - SOT-23-6 Marking

| Part No. | Marking | Part No. | Marking |
| :---: | :---: | :---: | :---: |
| AIC1899PG | $1899 P$ | AIC1899GG | 1899G |

## ABSOLUTE MAXIMUM RATINGS

IN, SHDN, FB, SS to GND ..... -0.3 V to +6 V
LX to GND ..... -0.3 V to +27 V
LX Pin RMS Current ..... 0.14 A
Operating Temperature Range ..... $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$
Junction Temperature ..... $125^{\circ} \mathrm{C}$
Storage Temperature Range ..... $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
Lead Temperature (soldering, 10s) ..... $260^{\circ} \mathrm{C}$
Thermal Resistance Junction to Case ..... $130^{\circ} \mathrm{C} / \mathrm{W}$
Thermal Resistance Junction to Ambient ..... $220^{\circ} \mathrm{C} / \mathrm{W}$
(Assume no ambient airflow, no heatsink)

Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

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## ELECTRICAL CHARACTERISTICS

$\left(\mathrm{V}_{\text {IN }}=\mathrm{V} \overline{\mathrm{SHDN}}=3 \mathrm{~V}, \mathrm{FB}=\mathrm{GND}, \mathrm{SS}=\right.$ Open, $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise specified) (Note 1)

| PARAMETER | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Input Supply Range | VIN |  | 2.5 |  | 5.5 | V |
| Output Voltage Adjust Range | VOUT |  |  |  | 24 | V |
| $\mathrm{V}_{\text {IN }}$ Undervoltage Lockout | UVLO | $\mathrm{V}_{\text {IN }}$ rising, 50 mV hysteresis |  | 2.2 |  | V |
| Quiescent Current | In | $\mathrm{V}_{\mathrm{FB}}=1.3 \mathrm{~V}$, not switching |  | 0.1 | 0.2 | mA |
|  |  | $\mathrm{V}_{\mathrm{FB}}=1.0 \mathrm{~V}$, switching |  | 1 | 5 |  |
| Output Current | lout | $\mathrm{V}_{\text {in }}=3 \mathrm{~V}$, Vout $=15 \mathrm{~V}$ |  | 15 |  | mA |
|  |  | $\mathrm{V}_{\text {in }}=3.3 \mathrm{~V}$, Vout $=15 \mathrm{~V}$ |  | 17 |  |  |
| Shutdown Supply Current |  | $V \overline{\text { SHDN }}=0, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ |  | 0.01 | 0.5 | $\mu \mathrm{A}$ |
|  |  | $V \overline{\text { SHDN }}=0$ |  | 0.01 | 10 | $\mu \mathrm{A}$ |
| ERROR AMPLIFIER |  |  |  |  |  |  |
| Feedback Regulation Set Point | $\mathrm{V}_{\mathrm{FB}}$ |  | 1.205 | 1.23 | 1.255 | V |
| FB Input Bias Current | $\mathrm{I}_{\text {FB }}$ | $\mathrm{V}_{\mathrm{FB}}=1.24 \mathrm{~V}$ |  | 21 | 80 | nA |
| Line Regulation |  | $2.6 \mathrm{~V}<\mathrm{V}_{\text {IN }}<5.5 \mathrm{~V}$ |  | 0.05 | 0.20 | \%/V |
| OSCILLATOR |  |  |  |  |  |  |
| Frequency | fosc |  | 800 | 1000 | 1700 | KHz |
| Maximum Duty Cycle | DC |  | 80 | 82 |  | \% |
| POWER SWITCH |  |  |  |  |  |  |
| On-Resistance | $\mathrm{R}_{\mathrm{DS}(\mathrm{ON})}$ | $\mathrm{Vin}=5 \mathrm{~V}$ |  | 1.2 | 1.6 | $\Omega$ |
| Leakage Current | lıX(OFF) | $\mathrm{V}_{L X}=24 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ |  | 0.1 | 1 | $\mu \mathrm{A}$ |
|  |  | $V_{L X}=24 \mathrm{~V}$ |  |  | 10 |  |
| SOFT-START |  |  |  |  |  |  |
| Reset Switch Resistance |  | Guaranteed By Design |  |  | 100 | $\Omega$ |
| Charge Current |  | $\mathrm{V}_{\text {SS }}=1.2 \mathrm{~V}$ | 1.5 | 4 | 7.0 | $\mu \mathrm{A}$ |
| CONTROL INPUT |  |  |  |  |  |  |
| Input Low Voltage | $\mathrm{V}_{\text {IL }}$ | $\mathrm{V} \overline{\text { SHDN }}, \mathrm{V}_{\text {IN }}=2.5 \mathrm{~V}$ to 5.5 V |  |  | 0.3 | V |
| Input High Voltage | $\mathrm{V}_{\mathrm{IH}}$ | $\mathrm{V} \overline{\text { SHDN }}, \mathrm{V}$ IN $=2.5 \mathrm{~V}$ to 5.5 V | 1.0 |  |  | V |
| $\overline{\text { SHDN }}$ Input Current | ISHDN | $V \overline{\text { SHDN }}=1.8 \mathrm{~V}$ |  | 25 | 50 | $\mu \mathrm{A}$ |
|  |  | $\mathrm{V} \overline{\text { SHDN }}=0$ |  | 0.01 | 0.1 |  |

Note 1: Specifications are production tested at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$. Specifications over the $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ operating temperature range are assured by design, characterization and correlation with Statistical Quality Controls (SQC).

## TYPICAL PERFORMANCE CHARACTERISTICS



Fig. 2 Switching Frequency vs. Temperature


Fig. 4 Efficiency vs. Output Current


Fig. 6 Load Regulation (L1=10 $\mu \mathrm{H}$ )


Fig. 3 Feedback Pin Voltage


Fig. 5 Efficiency vs. output current


Fig. 7 Load Regulation (L1=22 $\mu \mathrm{H}$ )

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)


Fig. 8 Frequency vs. Supply Voltage


Fig. 10 Switching Current


Fig. 12 Operation Waveform
$\left(\mathrm{V}_{\text {IN }}=3 \mathrm{~V} ; \mathrm{V}_{\text {OUT }}=15 \mathrm{~V}\right.$, l lout $=15 \mathrm{~mA}$, Test circuit as Fig.1)


Fig. $9 R_{\text {DS-ON }}$ vs. Supply Voltage


Fig. 11 Non-Switching Current


Fig. 13 Start-up Waveform
$\left(\mathrm{V}_{\text {IN }}=3 \mathrm{~V}\right.$; $\mathrm{V}_{\text {OUT }}=15 \mathrm{~V}$, I lout $=15 \mathrm{~mA}$, Test circuit as Fig.1)

AIC1899

## BLOCK DIAGRAM



## PIN DESCRIPTIONS

PIN 1: LX - Power Switching Connection. Connect LX to inductor and output rectifier. Keep the distance between the components as close to LX as possible.

PIN 2: GND - Ground.
PIN 3: FB - Feedback Input. Connect a resistive voltage-divider from the output to FB to set the output voltage.
PIN 4: $\overline{\mathrm{SHDN}}$ - Shutdown Input. Drive $\overline{\text { SHDN }}$ low to turn off the converter. To automatically start the converter, connect SHDN to IN. Drive
$\overline{\text { SHDN }}$ with a slew rate of $0.1 \mathrm{~V} / \mu \mathrm{s}$ or greater. Do not leave $\overline{\text { SHDN }}$ unconnected. $\overline{\text { SHDN }}$ draws up to $50 \mu \mathrm{~A}$.
PIN 5: SS

PIN 6: IN

Soft-Start Input. Connect a soft-start capacitor from SS to GND in order to soft-start the converter. Leave SS open to disable the soft-start function.
Internal Bias Voltage Input. Connect IN to the input voltage source. Bypass IN to GND with a capacitor sitting as close to $\mathbb{I N}$ as possible.

## APPLICATION INFORMATION

The AIC1899 operates well with a variety of external components. The components in Figure 1 are suitable for most applications. See the following sections to optimize external components for a particular application.

## Inductor Selection

A $22 \mu \mathrm{H}$ inductor is recommended for most AIC1899 applications. Although small size and high efficiency are major concerns, the inductor should have low core losses at 1.0 MHz and low DCR (copper wire resistance).
Inductor selection depends on input voltage, output voltage, maximum current, size, and availability of inductor values. Other factors can include efficiency and ripple voltage. Inductors are specified by their inductance (L), peak current ( $\mathrm{L}_{\mathrm{L}(\mathrm{PK})}$ ), and resistance (DCR). The following step-up circuit equations are useful in choosing the inductor values based on the application. They allow the trading of peak current and inductor value while considering component availability and cost.
The equation used here assumes a constant K, which is the ratio of the inductor peak-to-peak AC current to average DC inductor current. A good compromise between the size of the inductor versus loss and output ripple is to choose a K of 0.3 to 0.5 . The peak inductor current is then given by:
$i_{L(p k)}=\frac{I_{o(\text { max })} \cdot V_{o}}{\eta \cdot V_{i(\text { min })}} \cdot\left(1+\frac{K}{2}\right)$
where:
$\mathrm{I}_{\mathrm{O}(\max )}$ : Maximum output current, (A)
$\mathrm{V}_{\mathrm{i}(\mathrm{min})}$ : Minimum input voltage, (V)
$\eta$ : Conversion efficiency, 0.8

$$
K=\frac{\Delta i_{L}}{I_{L}}: \text { Ratio of the inductor peak-to-peak }
$$

AC current to average DC inductor current

The inductance value is then given by:

$$
L=\frac{V_{i(\min )}^{2} \cdot \eta \cdot D}{K \cdot f \cdot V_{o} \cdot I_{o(\max )}}
$$

where:
$D=$ Duty cycle $=\frac{V_{i(\min )}-\left(V_{f}+V_{o}\right)}{I_{i(\max )} \cdot R_{d s(o n)}-\left(V_{f}+V_{o}\right)}$
$V_{f}$ : Catch diode forward drop
$f$ : Switching frequency

## Capacitor Selection

The AIC1899 operates with both tantalum and ceramic output capacitors. When using tantalum capacitors, the zero caused by the ESR of the tantalum is used to ensure stability. When using ceramic capacitors, the zero due to the ESR will be at too high a frequency to be useful in stabilizing the control loop. When using ceramic capacitors, add a feedforward capacitor to increase the phase margin, improving the control-loop stability.

## Diode Selection

Schottky diodes, with their low forward voltage drop and fast reverse recovery, are the ideal choices for AIC1899 applications. The forward voltage drop of an Schottky diode represents the conduction losses in the diode, while the diode capacitance (CT or CD) represents the switching losses. For diode selection, both forward voltage drop and diode capacitance need to be considered. Schottky diodes with higher current ratings usually have lower forward voltage drop
and larger diode capacitance, which can cause significant switching losses at the 1.0 MHz switching frequency of AIC1899.

## Setting the Output Voltage

The AIC1899 operates with an adjustable output from Vin to 24 V . Connect a resistive voltage divider from the output to FB (see Fig.1).

Calculate $R_{1}$ and $R_{2}$ using the equation:

$$
\frac{R_{1}}{R_{2}}=\left(\frac{V_{0}}{V_{F B}}-1\right)
$$

where $V_{F B}$, the step-up regulator feedback set point, is 1.23 V . Connect the resistive-divider as close to the IC as possible.

## APPLICATION EXAMPLES



Fig. 14 1-Cell Li-Ion boost converter for OLED Application

PHYSICAL DIMENSIONS (unit: mm)

- TSOT-23-6


| $\begin{aligned} & S \\ & Y \\ & \text { Y } \\ & \text { B } \\ & \text { O } \\ & \text { L } \end{aligned}$ | TSOT-23-6 |  |
| :---: | :---: | :---: |
|  | MILLIMETERS |  |
|  | MIN. | MAX. |
| A | - | 1.00 |
| A1 | 0 | 0.10 |
| A2 | 0.70 | 0.90 |
| b | 0.30 | 0.50 |
| c | 0.08 | 0.22 |
| D | 2.80 | 3.00 |
| E | 2.60 | 3.00 |
| E1 | 1.50 | 1.70 |
| e | 0.95 BSC |  |
| e1 | 1.90 BSC |  |
| L | 0.30 | 0.60 |
| L1 | 0.60 REF |  |
| $\theta$ | $0^{\circ}$ | $8^{\circ}$ |

Note : 1. Refer to JEDEC MO-193AA.
2. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion or gate burrs shall not exceed 6 mil per side.
3. Dimension "E1" does not include inter-lead flash or protrusions.
4. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.

SOT-23-6


| S <br> Y <br> M <br> B <br> B <br> L | SOT-23-6 |  |
| :---: | :---: | :---: |
|  | MILLIMETERS |  |
|  | MIN. | MAX |
| A | 0.95 | 1.45 |
| A1 | 0.05 | 0.15 |
| A2 | 0.90 | 1.30 |
| b | 0.30 | 0.50 |
| c | 0.08 | 0.22 |
| D | 2.80 | 3.00 |
| E | 2.60 | 3.00 |
| E1 | 1.50 | 1.70 |
| e | 0.95 BSC |  |
| e1 | 1.90 BSC |  |
| L | 0.30 | 0.60 |
| L1 | 0.42 REF |  |
| $\theta$ | $0^{\circ}$ | $8^{\circ}$ |

Note : 1. Refer to JEDEC MO-178AB.
2. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion or gate burrs shall not exceed 10 mil per side.
3. Dimension "E1" does not include inter-lead flash or protrusions.
4. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.

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